





	ITC100P	Units
Hook Switch Breakdown Voltage	350	V
Bridge Rectifier Reverse		
Voltage	350	V
Darlington Collector Current	120	mA

Features

- Small 16 Pin SOIC Package (PCMCIA Compatible)
- Board Space and Cost Savings
- No Moving Parts
- 3750V_{RMS} Input/Output Isolation
 FCC Compatible Part 68
- Photodarlington Hook Switch
- Full-Wave Bridge Rectifier
- · Darlington Transistor for Electronic Inductor "Dry" Circuits
- · Half Wave Current Detector for Ring Signal or Loop Current Detect
- · JEDEC Standard Pin Out

Computer Telephony Integration

Applications Data/Fax Modem · Voice Mail Systems

Telephone Sets

Set Top Box Modems

Description

The Integrated Telecom Circuit combines a high voltage optically isolated photodarlington, bridge rectifier, Darlington transistor and optocoupler into one 16 pin SOIC package, consolidating designs and reducing component count in telecom applications. The ITC100's optocoupler provides for half wave detection of ring signals.

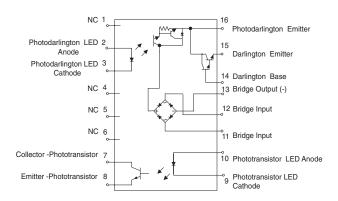
Approvals

- UL Recognized
- EN 60950

Ordering Information

Part #	Description
ITC100P	16 Pin SOIC (50/Tube)
ITC100PTR	16 Pin SOIC (1000/Reel)

Pin Configuration





Absolute Maximum Ratings (@ 25° C)

Parameter	Min	Тур	Max	Units
Total Package Dissipation	-	-	1 ¹	W
Isolation Voltage				
Input to Output	3750	-	-	V _{RMS}
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature (10 Seconds Max.)	-	-	+220	°C

¹ Above 25° derate linerity 8.33mw/°C

Total Power Dissipation (PD):

$$\begin{split} P_{D} = & P_{HOOKSWITCH} + P_{BRIDGE} + P_{DARLINGTON} + P_{LED} \\ P_{D} = & (R_{DS}(on)) (I^2_{L}) + 2(V_F)(I_{L}) + (V_{CE})(I_{L}) + (V_{LED})(I_F) \end{split}$$
WHERE:

R_{DS}(on) = Maximum realy on resistance

I_L V_F = Maximum loop current

= Maximum diode forward voltage

V_{CE} = Maximum voltage collector to emitter

= Maximum LED forward voltage V_{LED}

= Maximum LED current I_{F}

Electrical Characteristics

Parameter	Condition	Symbol	Min	Тур	Max	Units
Photodarlington Portion					1	
Collector-Emitter Breakdown voltage	I _C = 100uA	B _{VCEO}	350	-	-	V
Collector Dark Current	V _{CE} = 200V	I _{CEO}	-	-	100	nA
Collector Emitter Saturation Voltage	I _C = 100mA I _B = 150uA	V _{CE(S)}	-	-	1.2	V
Current Gain	Hfe	I _C = 40mA V _{CE} =2V	2500	-	40000	-
LED Input control Current	-	I _F	5	-	50	mA
LED input Voltage Drop	I _F = 5mA	V _F	0.9	1.2	1.4	V
LED Reverse Input Voltage	-	V _R	-	-	5	V
LED Reverse Input Current	I _R = 5V	I _R	-	-	10	mA
Phototransistor Portion						
Phototransitor Blocking Voltage	I _C = 10uA	B _{VCEO}	20	50	-	V
Phototransistor Dark Current	$V_{CC} = 5V$ $I_F = 0mA$	I _{CEO}	-	50	500	mA
Saturation Voltage	I _C = 2mA I _F = 16mA	V _{SAT}	-	0.3	0.5	V
Current Transfer Ratio	V _{CE} = 0.5V I _F = 6mA	CTR	33	400	-	%
LED Input control Current	$V_{CE} = 0.5V$ $I_{C} = 2mA$	١ _F	6	2	100	mA
LED input Voltage Drop	I _F = 5mA	V _F	0.9	1.2	1.4	V
LED Input Current (Detector must be off)	$V_{CE} = 5V$ $I_C = 10uA$	I _F	5	25	-	uA
Bridge Rectifier Portion						
Reverse Voltage	-	V _{RD}	-	-	350	V
Forward Voltage Drop	I _{FD} = 120mA	V _{FD}	-	-	1.1	V

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

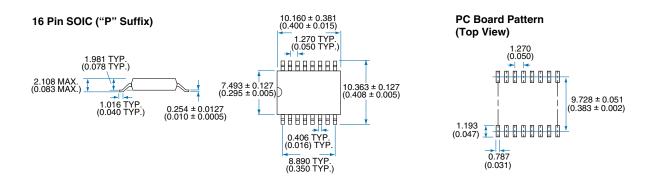


Electrical Characteristics

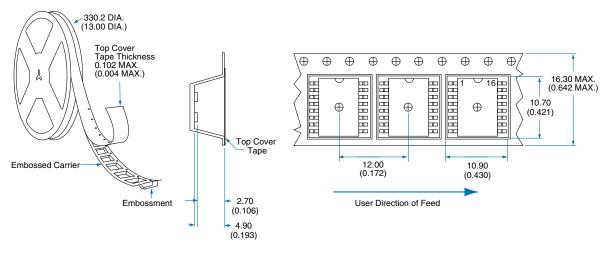
Parameter	Condition	Symbol	Min	Тур	Max	Units
Reverse Leakage Current	T _J = 25°C	I _{RD}	-	-	10	uA
	V _R = 350V					
	T _J = 85°C				50	uA
Forward Current Continuous		I _{FD}	-	-	140	mA
Forward Current Peak	T= 10mS	I _{FD}	-	-	0.5	А
Darlington Portion						
Collector Emitter Voltage	I _c =10mA DC	V _{CEO}	20	-	-	V
	I _B =0					
Collector Current Continous	V _C =3.5V	۱ _с	-	-	120	mA
Off – State Collector Emitter	V _{CE} =10V	I _{CEX}	-	-	1	uA
Leakage Current	I _B =0mA					
DC Gain Current	V _{CE} =5VDC	h _{FE}	300	-	-	-
	I _c =100mA					
Saturation Voltage	I _c =120mA	V _{CE(SAT)}	-	-	1.5	V
Total Harmonic Distortion	F ₀ =300Hz @	-	-	-	-80	dB
	-10dBm					
	I _C =40mA					



MECHANICAL DIMENSIONS



Tape and Reel Packaging for 16 Pin SOIC Package



Dimensions mm (inches)

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